

## MiniSKiiP<sup>®</sup> 3

### SKiiP 37NAB12T4V1

#### Features

- Trench 4 IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for
- electrical connectionsUL recognised: File no. E63532

## Typical Applications\*

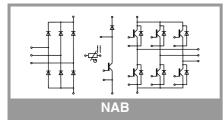
## Inverter up to 36 kVA

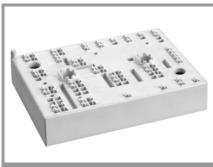
Typical motor power 22 kW

### Remarks

- Max. case temperature limited to  $T_C=125^{\circ}C$
- Product reliability results valid for T<sub>j</sub>≤150°C (recommended T<sub>i.op</sub>=-40...+150°C)
- T<sub>j,op</sub>=-40...+150°C)
  MiniSKiiP "Technical Explanations" and "Mounting Instructions" are part of the data sheet. Please refer to both documents for further information.

Absolut	te Maximum Ratings	5		
Symbol	Conditions		Values	Unit
Inverter	- IGBT			
V <sub>CES</sub>	T <sub>j</sub> = 25 °C		1200	V
lc	λ <sub>paste</sub> =0.8 W/(mK)	T <sub>s</sub> = 25 °C	90	A
	T <sub>j</sub> = 175 °C	T <sub>s</sub> = 70 °C	73	Α
l <sub>c</sub>	λ <sub>paste</sub> =2.5 W/(mK)	T <sub>s</sub> = 25 °C	106	Α
	T <sub>j</sub> = 175 °C	T <sub>s</sub> = 70 °C	86	Α
I <sub>Cnom</sub>			75	Α
I <sub>CRM</sub>	I <sub>CRM</sub> = 3 x I <sub>Cnom</sub>		225	Α
V <sub>GES</sub>			-20 20	V
t <sub>psc</sub>	$V_{CC} = 800 V$ $V_{GE} \le 15 V$ $V_{CES} \le 1200 V$	T <sub>j</sub> = 150 °C	10	μs
Tj			-40 175	°C
Choppe	r - IGBT			
V <sub>CES</sub>	$T_i = 25 \text{ °C}$		1200	V
	$\lambda_{\text{paste}} = 0.8 \text{ W/(mK)}$	T <sub>s</sub> = 25 °C	90	A
	$T_{i} = 175 \text{ °C}$	$T_{s} = 70 ^{\circ}C$	73	A
lc	,	$T_s = 25 \text{ °C}$	106	A
	λ <sub>paste</sub> =2.5 W/(mK) T <sub>i</sub> = 175 °C	$T_s = 20  ^{\circ}C$	86	A
	.,	15-70 0	75	A
I <sub>Cnom</sub>	I <sub>CRM</sub> = 3 x I <sub>Cnom</sub>		225	A
V <sub>GES</sub>	ICRM - O X ICnom		-20 20	
t <sub>psc</sub>	$V_{CC} = 800 V$ $V_{GE} \le 15 V$ $V_{CES} \le 1200 V$	T <sub>j</sub> = 150 °C	10	μs
Ti			-40 175	°C
Inverse	- Diode			
	T <sub>i</sub> = 25 °C		1200	V
V <sub>RRM</sub>	$\lambda_{\text{paste}} = 0.8 \text{ W/(mK)}$	T <sub>s</sub> = 25 °C	83	A
·r	$T_i = 175 \text{ °C}$	$T_s = 70 \degree C$	66	A
IF	λ <sub>paste</sub> =2.5 W/(mK)	$T_s = 25 \text{ °C}$	95	A
	$T_i = 175 \text{ °C}$	$T_s = 70 \text{ °C}$	76	A
IEnom	1	.5 .0 0	75	A
I <sub>Fnom</sub>	I <sub>FRM</sub> = 3 x I <sub>Fnom</sub>		225	A
I <sub>FSM</sub>	$t_p = 10 \text{ ms}, \sin 180^\circ$	². T₁ = 150 °C	430	A
T <sub>j</sub>		, .]	-40 175	°C
-	eeling - Diode			
V <sub>RRM</sub>	$T_i = 25 ^{\circ}\text{C}$		1200	V
	-	T <sub>s</sub> = 25 °C	83	A
l <sub>F</sub>	λ <sub>paste</sub> =0.8 W/(mK) T <sub>i</sub> = 175 °C	$T_s = 25 \text{ C}$ $T_s = 70 \text{ °C}$		
1_	-	$T_s = 70$ °C $T_s = 25$ °C	66	A
l <sub>F</sub>	$\lambda_{\text{paste}}$ =2.5 W/(mK) T <sub>j</sub> = 175 °C		95	A
1	1,-175 0	T <sub>s</sub> = 70 °C	76	A
I <sub>Fnom</sub>			75	A
I <sub>FRM</sub>	$I_{FRM} = 3 \times I_{Fnom}$	T 450.00	225	A
I <sub>FSM</sub>	t <sub>p</sub> = 10 ms, sin 180°	′, I <sub>j</sub> = 150 °C	430	A
Tj			-40 175	°C





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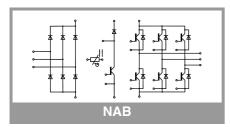
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Absolute	e Maximum Rating	S				
Symbol	Conditions			Values		Unit
Rectifier	- Diode					
V <sub>RRM</sub>	T <sub>j</sub> = 25 °C			1600		V
IF	λ <sub>paste</sub> =0.8 W/(mK)	T <sub>s</sub> = 25 °C		81		Α
	T <sub>j</sub> = 150 °C	T <sub>s</sub> = 70 °C		60		Α
l <sub>F</sub>	λ <sub>paste</sub> =2.5 W/(mK)	T <sub>s</sub> = 25 °C		92		Α
	T <sub>j</sub> = 150 °C	T <sub>s</sub> = 70 °C		68		Α
<b>I</b> <sub>Fnom</sub>				25		Α
I <sub>FSM</sub>	10 ms	T <sub>j</sub> = 25 °C		700		Α
	sin 180°	T <sub>j</sub> = 150 °C		490		Α
l <sup>2</sup> t	10 ms	T <sub>j</sub> = 25 °C		2400		A <sup>2</sup> s
	sin 180°	T <sub>j</sub> = 150 °C		1200		A <sup>2</sup> s
Tj				-40 150		°C
Module						
I <sub>t(RMS)</sub>	T <sub>terminal</sub> = 80 °C, 20	A per spring		80		А
T <sub>stg</sub>			-40 125			°C
V <sub>isol</sub>	AC sinus 50 Hz, 1	min		2500		V
Charact	eristics		1			
Symbol	Conditions		min.	typ.	max.	Unit
Inverter -	- IGBT					
V <sub>CE(sat)</sub>	I <sub>C</sub> = 75 A	T <sub>j</sub> = 25 °C		1.85	2.10	V
	V <sub>GE</sub> = 15 V chiplevel	T <sub>i</sub> = 150 °C		2.25	2.45	V
V <sub>CE0</sub>		T <sub>i</sub> = 25 °C		0.80	0.90	v
V CEU	- chiplevel	$T_i = 150 \text{ °C}$		0.70	0.80	v
r <sub>CE</sub>	V <sub>GE</sub> = 15 V	$T_i = 25 \text{ °C}$		14	16	mΩ
-CE	chiplevel	$T_i = 150 \text{ °C}$		21	22	mΩ
V <sub>GE(th)</sub>	V <sub>GE</sub> = V <sub>CE</sub> V, I <sub>C</sub> = 3	1 '	5	5.8	6.5	V
	$V_{GE} = 0 V, V_{CE} = 12$			0.1	0.3	mA
Cies		f = 1 MHz		4.40	0.0	nF
Coes	V <sub>CE</sub> = 25 V	f = 1 MHz		0.29		nF
Cres	V <sub>GE</sub> = 0 V	f = 1 MHz		0.24		nF
Q <sub>G</sub>	- 8 V+ 15 V			425		nC
⊂G R <sub>Gint</sub>	$T_i = 25 \text{ °C}$			10		Ω
t <sub>d(on)</sub>	$V_{CC} = 600 V$	T <sub>i</sub> = 150 °C	_	150		ns
t <sub>r</sub>	I <sub>C</sub> = 75 A	T <sub>i</sub> = 150 °C		35		ns
Eon	$-R_{G on} = 2 \Omega$	$T_i = 150 ^{\circ}C$		9.7		mJ
t <sub>d(off)</sub>	$R_{G off} = 2 \Omega$	$T_i = 150 ^{\circ}C$		355		ns
t <sub>f</sub>	_	$T_{j} = 150 \text{ °C}$		60		ns
-1	_					
E <sub>off</sub>	V <sub>GE</sub> = +15/-15 V	T <sub>j</sub> = 150 °C		6.8		mJ



K/W

K/W

0.58

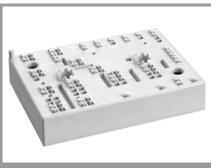
0.44

per IGBT,  $\lambda_{\text{paste}}$ =0.8 W/(mK)

per IGBT,  $\lambda_{paste}$ =2.5 W/(mK)

R<sub>th(j-s)</sub>

R<sub>th(j-s)</sub>



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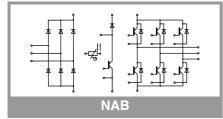
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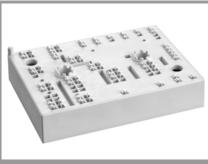
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Characte	ristics					
Symbol	Conditions		min.	typ.	max.	Unit
Chopper	- IGBT					
V <sub>CE(sat)</sub>	I <sub>C</sub> = 75 A	T <sub>i</sub> = 25 °C		1.85	2.10	V
. ,	V <sub>GE</sub> = 15 V	T <sub>i</sub> = 150 °C		2.25	2.45	v
V	chiplevel	$T_i = 25 °C$		0.80		V
V <sub>CE0</sub>	chiplevel	$T_{i} = 150 \text{ °C}$		0.80		V
r	V <sub>GE</sub> = 15 V	$T_{i} = 25 ^{\circ}C$		14		ν mΩ
r <sub>CE</sub>	chiplevel	$T_i = 150 ^{\circ}C$		21		mΩ
Varma	$V_{GE} = V_{CE} V$ , $I_C = 3$		5	5.8		V
V <sub>GE(th)</sub> I <sub>CES</sub>	$V_{GE} = 0 V, V_{CE} = 1200 V, T_i = 25 °C$		5	0.1		mA
Q <sub>G</sub>	- 8 V+ 15 V	00 V, IJ=23 O		425	0.0	nC
	$T_i = 25 °C$			10.0		Ω
	$V_{CC} = 600 V$	T <sub>i</sub> = 150 °C		150		-
t <sub>d(on)</sub>	$I_{\rm C} = 75 \rm{A}$	$T_i = 150 \text{ °C}$		35		ns
t <sub>r</sub>	$R_{G on} = 2 \Omega$	$T_{i} = 150 \text{ C}$ $T_{i} = 150 \text{ °C}$		9.7		ns
E <sub>on</sub>	$R_{G off} = 2 \Omega$	$T_j = 150 \text{ C}$ $T_i = 150 \text{ °C}$		9.7 355		mJ
t <sub>d(off)</sub>	-					ns
t <sub>f</sub>	-	T <sub>j</sub> = 150 °C		60		ns
E <sub>off</sub>	V <sub>GE</sub> = +15/-15 V	T <sub>j</sub> = 150 °C		6.8		mJ
R <sub>th(j-s)</sub>	per IGBT, λ <sub>paste</sub> =0.8	3 W/(mK)		0.58		K/W
R <sub>th(j-s)</sub>	per IGBT, λ <sub>paste</sub> =2.5	5 W/(mK)		0.44		K/W
Inverse -						
$V_F = V_{EC}$	I <sub>F</sub> = 75 A	T <sub>i</sub> = 25 °C		2.17	2.49	V
	V <sub>GE</sub> = 0 V	T <sub>i</sub> = 150 °C		2.11	2 4 2	v
N/	chiplevel	-				
V <sub>F0</sub>	chiplevel	T <sub>j</sub> = 25 °C		1.30		V
		T <sub>j</sub> = 150 °C		0.90		-
r <sub>F</sub>	chiplevel	T <sub>j</sub> = 25 °C		12	2.45 0.90 0.80 16 22 6.5 0.3	mΩ
	I <sub>F</sub> = 75 A	T <sub>j</sub> = 150 °C		16	18	mΩ
	$di/dt_{off} = 1940 \text{ A/}\mu\text{s}$	T <sub>j</sub> = 150 °C		62		A
Q <sub>rr</sub>	$V_{GE} = -15 V$			12.6		μC
Err	V <sub>CC</sub> = 600 V	T <sub>j</sub> = 150 °C		4.9		mJ
R <sub>th(j-s)</sub>	per Diode, $\lambda_{\text{paste}}=0$ .			0.75		K/W
R <sub>th(j-s)</sub>	per Diode, $\lambda_{\text{paste}}=2$ .	5 W/(mK)		0.61		K/W
Freewhee	eling - Diode					
$V_F = V_{EC}$	I <sub>F</sub> = 75 A	T <sub>j</sub> = 25 °C		2.17	2.49	V
	V <sub>GE</sub> = 0 V chiplevel	T <sub>j</sub> = 150 °C		2.11	2.42	V
V <sub>F0</sub>	- chiplevel	T <sub>j</sub> = 25 °C		1.30	1.50	V
		T <sub>j</sub> = 150 °C		0.90	1.10	V
r <sub>F</sub>	chiplevel	T <sub>j</sub> = 25 °C		12	13	mΩ
		T <sub>j</sub> = 150 °C		16	18	mΩ
I <sub>RRM</sub>	I <sub>F</sub> = 75 A	T <sub>j</sub> = 150 °C		62		Α
Q <sub>rr</sub>	$di/dt_{off} = 1940 \text{ A/}\mu\text{s}$	T <sub>j</sub> = 150 °C		12.6		μC
Err	V <sub>GE</sub> = -15 V V <sub>CC</sub> = 600 V	T <sub>j</sub> = 150 °C		4.9		mJ
R <sub>th(j-s)</sub>	per Diode, $\lambda_{\text{paste}}=0.00$			0.75		K/W
R <sub>th(j-s)</sub>	per Diode, $\lambda_{\text{paste}}$ =2.			0.61		K/W





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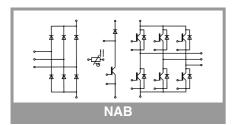
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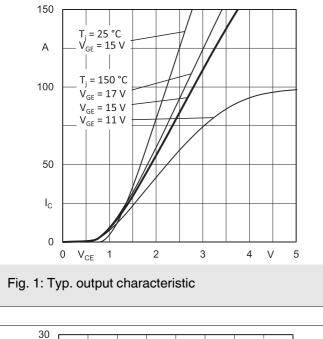
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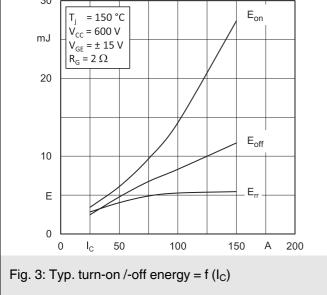
### Remarks

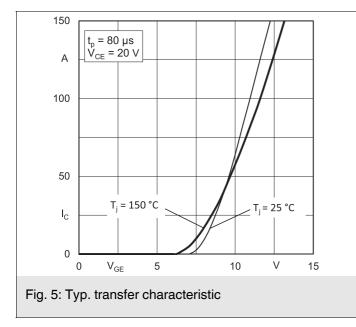
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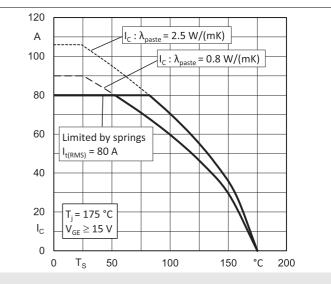
Characte	ristics					
Symbol	Conditions		min.	typ.	max.	Unit
Rectifier -	Diode					
$V_F = V_{EC}$	I <sub>F</sub> = 25 A	T <sub>j</sub> = 25 °C		1.00	1.21	V
	V <sub>GE</sub> = 0 V chiplevel	T <sub>j</sub> = 125 °C		0.90	1.10	V
V <sub>F0</sub>	chiplevel	T <sub>j</sub> = 25 °C		0.88	0.98	V
		T <sub>j</sub> = 125 °C		0.73	0.83	V
r <sub>F</sub>	chiplevel	T <sub>j</sub> = 25 °C		4.8	9.2	mΩ
		T <sub>j</sub> = 125 °C		6.8	11	mΩ
R <sub>th(j-s)</sub>	per Diode, $\lambda_{\text{paste}}$ =0.8 W/(mK)			0.9		K/W
R <sub>th(j-s)</sub>	per Diode, $\lambda_{paste}$ =2.5 W/(mK)			0.75		K/W
Module						
Ms	to heat sink		2		2.5	Nm
w				82		g
L <sub>CE</sub>						nH
Temperat	ure Sensor					
R <sub>100</sub>	$T_r = 100 \ ^{\circ}C$ , tolerance = 3 %			1670 ± 3%		Ω
R(T)	R(T)=1000Ω[1+ ], A = 7.635*10 <sup>-5</sup> B = 1.731*10 <sup>-5</sup> °	A(T-25°C)+B(T-25°C) <sup>2</sup> <sup>3</sup> °C <sup>-1</sup> , 'C <sup>-2</sup>				

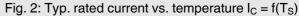


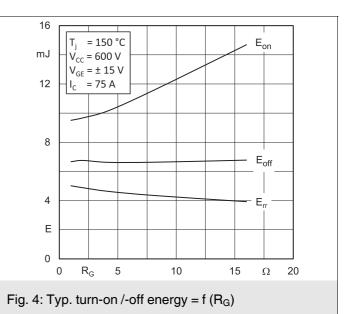


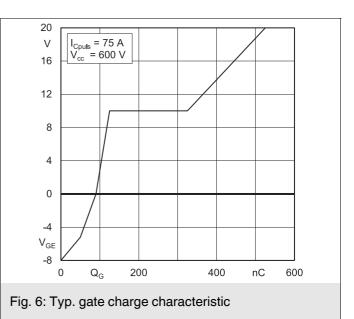




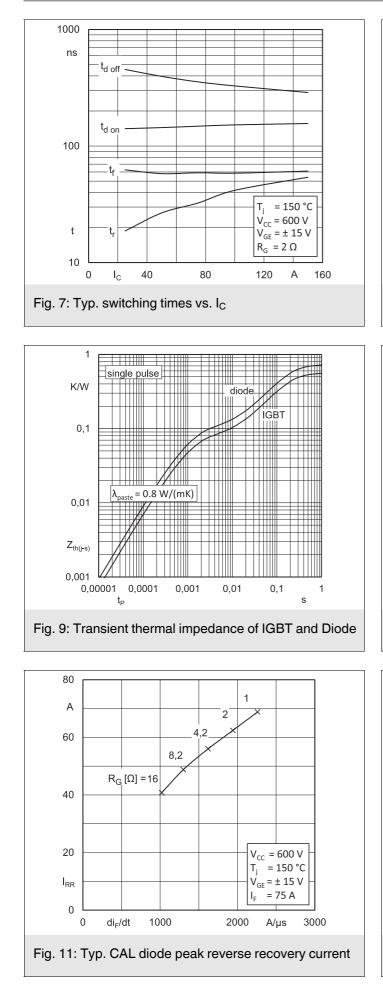








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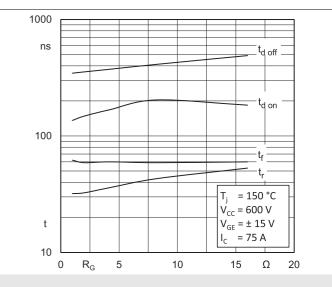


Fig. 8: Typ. switching times vs. gate resistor R<sub>G</sub>

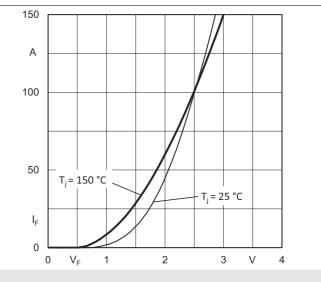
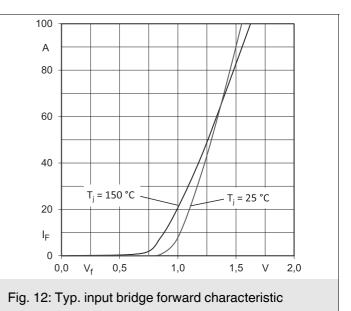
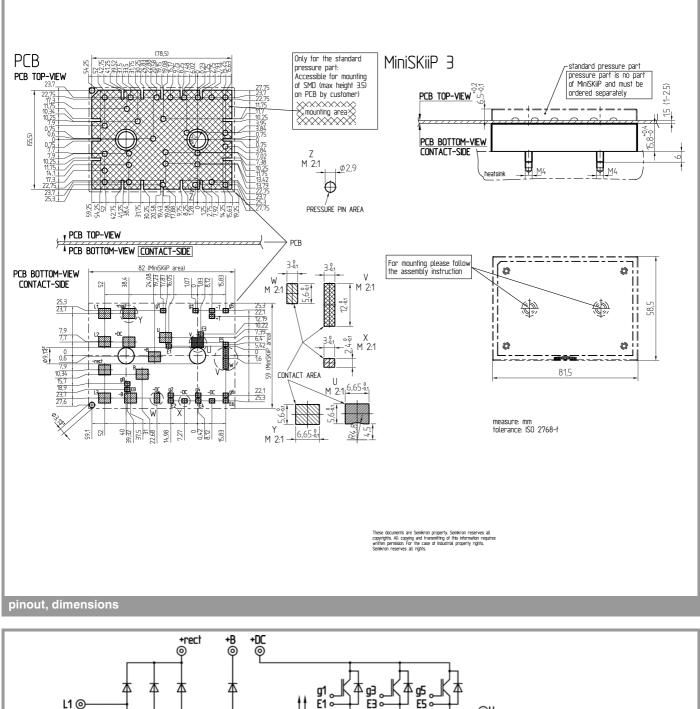
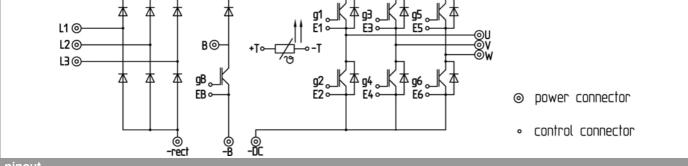


Fig. 10: CAL diode forward characteristic







pinout

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

#### **\*IMPORTANT INFORMATION AND WARNINGS**

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